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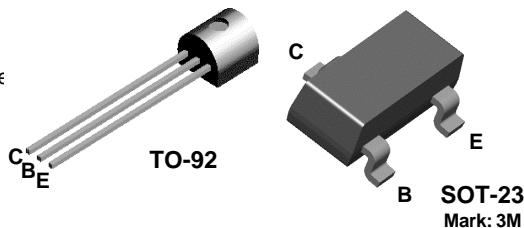
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2N5210/MMBT5210

NPN General Purpose Amplifier

This device is designed for low noise, high gain, general purpose amplifier applications at collector currents from 1 μ A to 50 mA.



Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	50	V
V_{CBO}	Collector-Base Voltage	50	V
V_{EBO}	Emitter-Base Voltage	4.5	V
I_C	Collector Current - Continuous	100	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max.		Units
		2N5210	MMBT5210	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

NPN General Purpose Amplifier

(continued)

Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
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OFF CHARACTERISTICS

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 1.0 \text{ mA}, I_B = 0$	50		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 0.1 \text{ mA}, I_E = 0$	50		V
I_{CBO}	Collector Cutoff Current	$V_{CB} = 35 \text{ V}, I_E = 0$		50	nA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_C = 0$		50	nA

ON CHARACTERISTICS

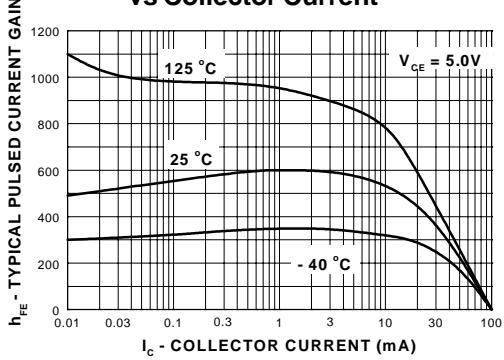
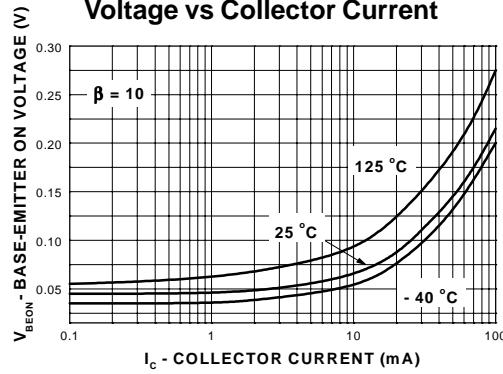
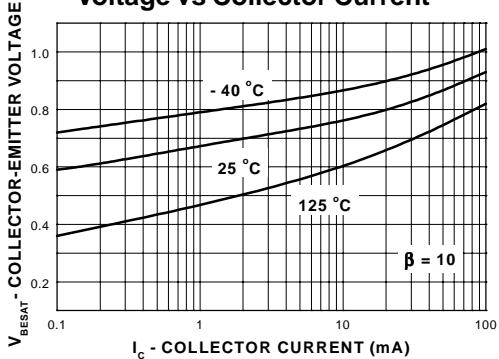
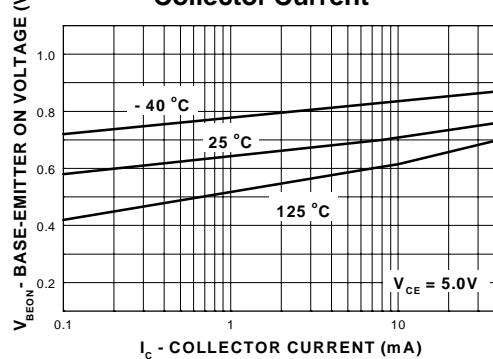
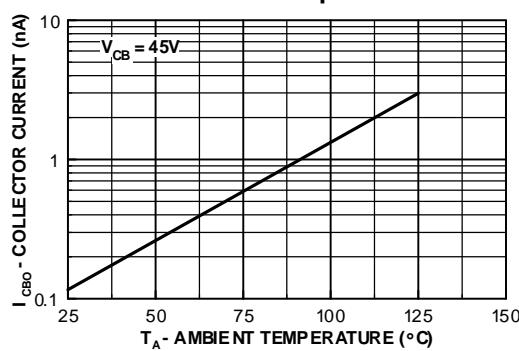
h_{FE}	DC Current Gain	$I_C = 100 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ $I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$ $I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}^*$	200 250 250	600	
$V_{CE(\text{sat})}$	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$		0.7	V
$V_{BE(\text{on})}$	Base-Emitter On Voltage	$I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$		0.85	V

SMALL SIGNAL CHARACTERISTICS

f_T	Current Gain - Bandwidth Product	$I_C = 500 \mu\text{A}, V_{CE} = 5.0 \text{ V},$ $f = 20 \text{ MHz}$	30		MHz
C_{cb}	Collector-Base Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0, f = 100 \text{ kHz}$		4.0	pF
h_{fe}	Small-Signal Current Gain	$I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V},$ $f = 1.0 \text{ kHz}$	250	900	
NF	Noise Figure	$I_C = 20 \mu\text{A}, V_{CE} = 5.0 \text{ V},$ $R_S = 22 \text{ k}\Omega, f = 10 \text{ Hz to } 15.7 \text{ kHz}$ $I_C = 20 \mu\text{A}, V_{CE} = 5.0 \text{ V},$ $R_S = 10 \text{ k}\Omega, f = 1.0 \text{ kHz}$		2.0 3.0	dB

*Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$

Typical Characteristics

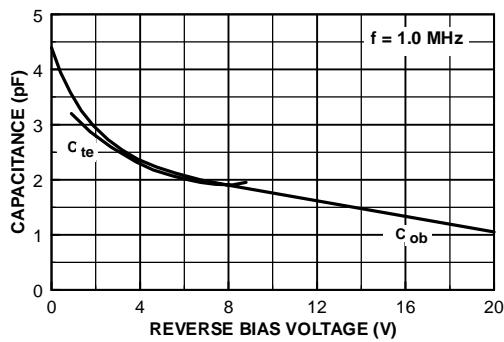
Typical Pulsed Current Gain
vs Collector CurrentCollector-Emitter Saturation
Voltage vs Collector CurrentBase-Emitter Saturation
Voltage vs Collector CurrentBase-Emitter ON Voltage vs
Collector CurrentCollector-Cutoff Current
vs Ambient Temperature

NPN General Purpose Amplifier

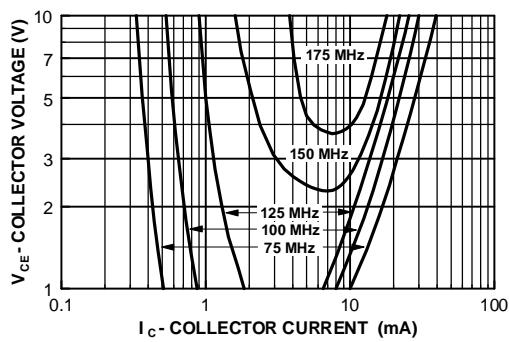
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Typical Characteristics (continued)

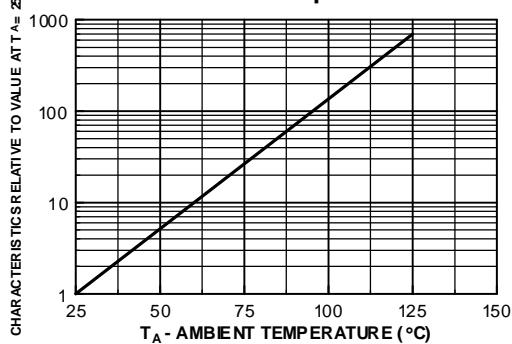
Input and Output Capacitance vs Reverse Bias Voltage



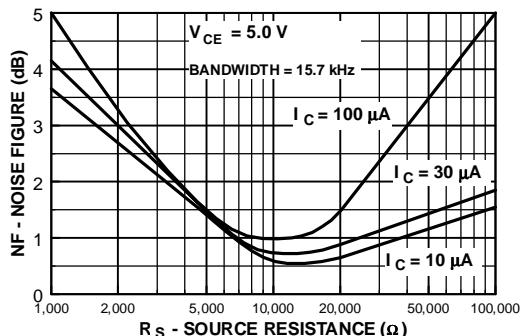
Contours of Constant Gain Bandwidth Product (f_T)



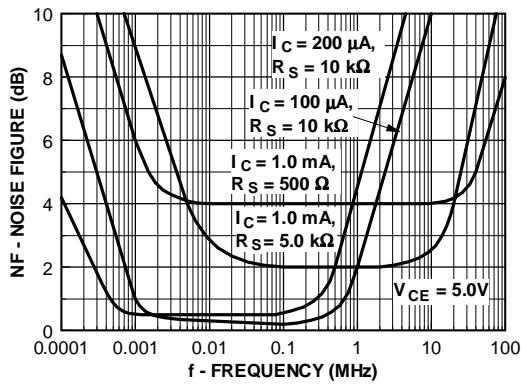
Normalized Collector-Cutoff Current vs Ambient Temperature



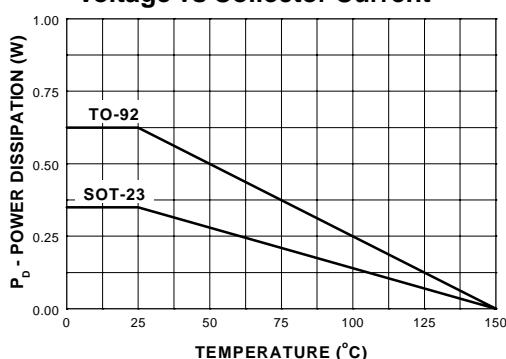
Wideband Noise Figure vs Source Resistance



Noise Figure vs Frequency



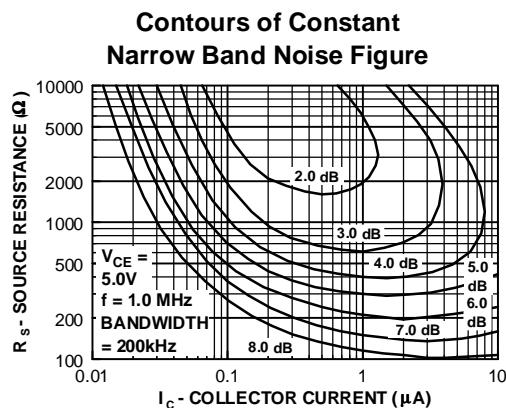
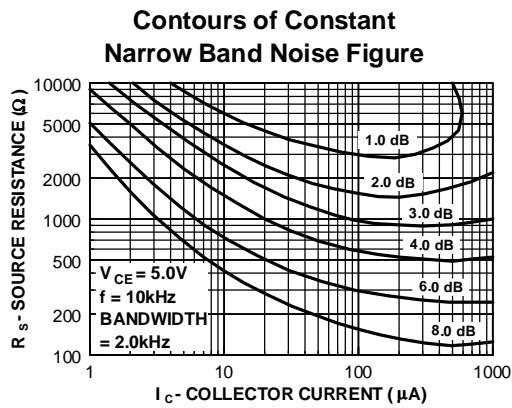
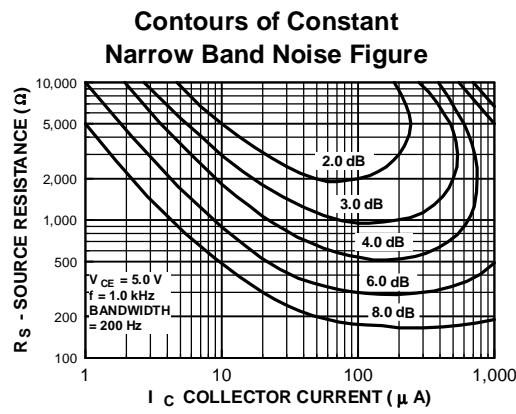
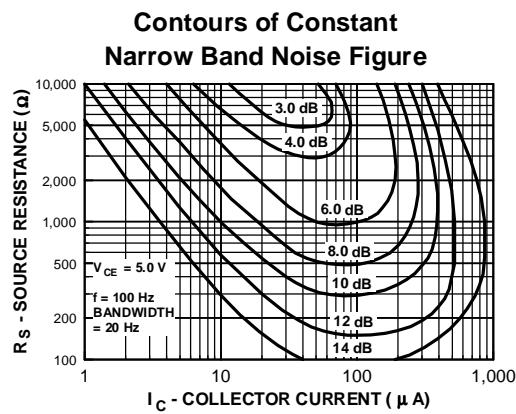
Base-Emitter Saturation Voltage vs Collector Current

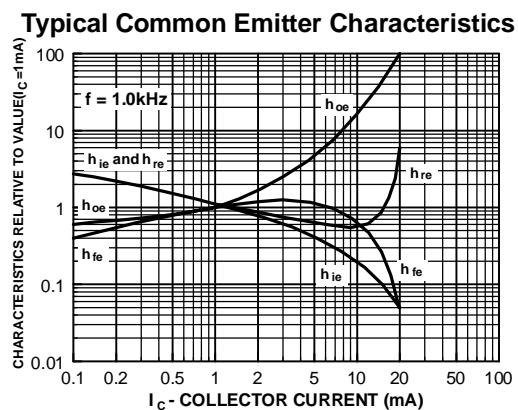
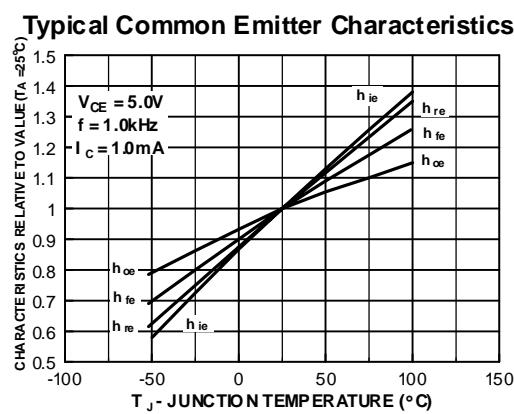
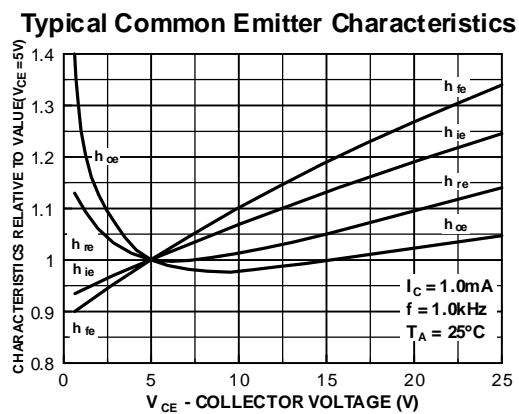


NPN General Purpose Amplifier

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Typical Characteristics (continued)



NPN General Purpose Amplifier
(continued)**Typical Common Emitter Characteristics** (f = 1.0 kHz)

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